SILICON POWER TRANSISTOR 2SB1669

PNP SILICON EPITAXIAL TRANSISTOR FOR HIGH-SPEED SWITCHING

The 2SB1669 is a power transistor that can be directly driven from the output of an IC. This transistor is ideal for OA and FA equipment such as motor and solenoid drivers.

FEATURES

NEC

- High DC current amplifier rate hFE ≥ 100 (VcE = -5.0 V, Ic = -0.5 A)
- · Z type available for surface mounting supported prodcuts

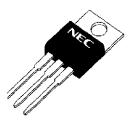
ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Parameter	Symbol	Conditions	Ratings	Unit
Collector to base voltage	Vсво		-60	V
Collector to emitter voltage	VCEO		-60	V
Emitter to base voltage	Vebo		-7.0	V
Collector current (DC)	IC(DC)		-3.0	А
Collector current (pulse)	C(pulse)	$PW \le 10 \text{ ms},$	-6.0	А
		duty cycle \leq 50%		
Base current (DC)	IB(DC)		-1.0	А
Total power dissipation	Р⊤	(Tc = 25°C)	25	W
		(T _A = 25°C)	1.5	W
Junction temperature	Tj		150	°C
Storage temperature	Tstg		-55 to +150	°C

ORDERING INFORMATION

Part No.	Package		
2SB1669	TO-220AB		
2SB1669-S	TO-262		
2SB1669-Z	TO-220SMD		

(TO-220AB)



(TO-262)



(TO-220SMD)



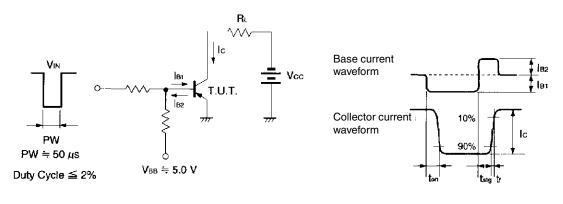
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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	$V_{CB} = -60 \text{ V}, \text{ I}_{E} = 0 \text{ A}$			-10	μA
DC current gain	hfe1	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}^{Note}$	100		400	-
	hfe2	$V_{CE} = -5 \text{ V}, \text{ Ic} = -3 \text{ A}^{\text{Note}}$	20			-
Collector saturation voltage	VCE(sat)	$I_{C} = -3.0 \text{ A}, I_{B} = -300 \text{ mA}^{Note}$			-1.0	V
Base saturation voltage	V _{BE(sat)}	$I_{C} = -3.0 \text{ A}, I_{B} = -300 \text{ mA}^{Note}$			-2.0	V
Gain bandwidth product	f⊤	$V_{CE} = -5.0 \text{ V}, \text{ Ic} = -0.5 \text{ A}$		5		MHz
Collector capacitance	Cob	$V_{CB} = -10 \text{ V}, \text{ I}_{E} = 0 \text{ A}, \text{ f} = 10 \text{ MHz}$		80		pF
Turn-on time	ton	lc = −2.0 A, RL = 15 Ω,		0.4		μs
Storage time	tstg	$I_{B1} = -I_{B2} = -200 \text{ mA}, \text{ Vcc} \cong -30 \text{ V}$		1.7		μs
Fall time	tr	Refer to the test circuit.		0.5		μs

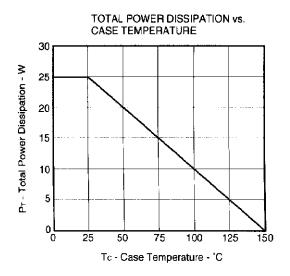
Note Pulse test PW \leq 350 μ s, duty cycle \leq 2%

SWITCHING TIME (ton, tstg, tf) TEST CIRCUIT

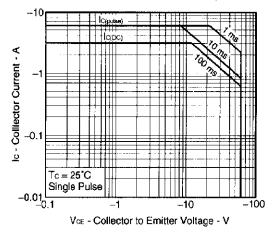


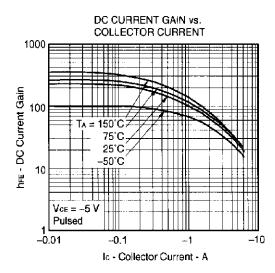
www.DataSheet4U.com

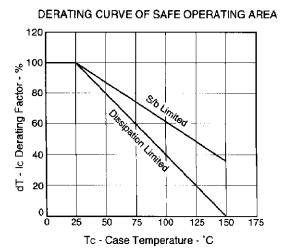




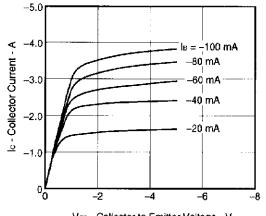
FORWARD BIAS SAFE OPERATING AREA



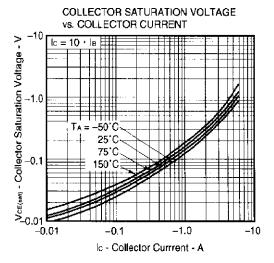




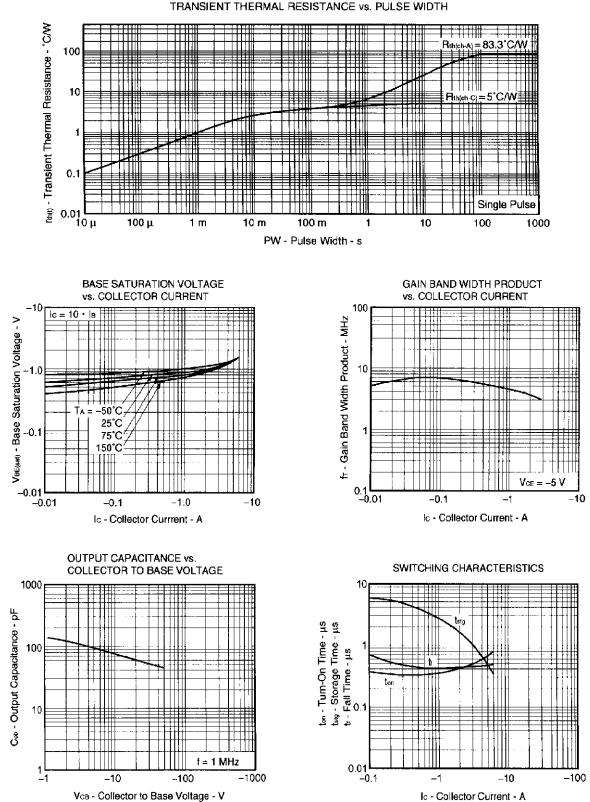
COLLECTOR CURRENT vs. COLLECTOR TO EMITTER VOLTAGE





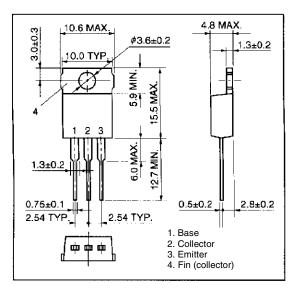




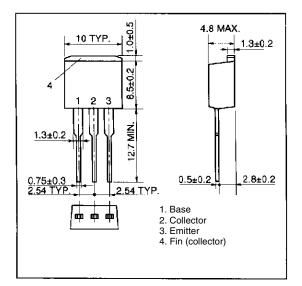


PACKAGE DRAWING (UNIT: mm)

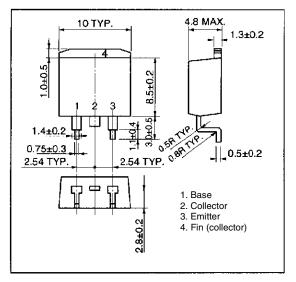
1) TO-220AB (MP-25)



2) TO-262 (MP-25 Fin Cut)



3) TO-220SMD (MP-25Z)



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